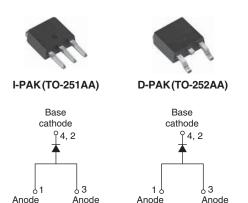


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High Performance Schottky Generation 5.0, 20 A



VS-20WT04FN

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA),				
<u> </u>	I-PAK (TO-251AA)				
I _{F(AV)}	20 A				
V_{R}	45 V				
V _F at I _F	0.53 V				
I _{RM} max.	7 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Single die				
E _{AS}	108 mJ				

Note

• V_F measured at 125 °C, connecting 2 anode pins

VS-20UT04

FEATURES

- 175 °C high performance Schottky diode
- · Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- Increased ruggedness for reverse avalanche capability
- RBSOA available
- · Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- · Specific for PV cells bypass diode
- High efficiency SMPS
- High frequency switching
- Output rectification
- · Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V _{RRM}		45	V		
V _F	20 Apk, T _J = 125 °C (typical, measured connecting 2 anode pins)	0.480	V		
T _J	Range	- 55 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20UT04 VS-20WT04FN	UNITS
Maximum DC reverse voltage	V_{R}	T _J = 25 °C	45	V

VS-20UT04, VS-20WT04FN

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 153 °C, rectangular waveform		20	Α
Maximum peak one cycle	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	900	A
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied ⁽¹⁾	220	, A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 7 \text{A}, L = 4.4 \text{mH}$		108	mJ
Repetitive avalanche current	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse		I _{AS} at T _J max.	Α

Note

(1) Measured connecting 2 anode pins

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	V _{FM} ⁽¹⁾⁽²⁾	10 A	T _J = 25 °C	0.505	0.540	V
		20 A		0.570	0.610	
		10 A	- T _J = 125 °C	0.415	0450	
		20 A		0.520	0.580	
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	-	100	μA
		T _J = 125 °C		-	7	mA
Junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		1900	-	pF
Series inductance	Ls	Measured lead to lead 5 mm from package body		-	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs

Notes

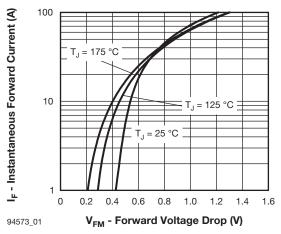
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

(2) Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.2	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}		0.3	C/VV
Approximate weight			2	g
Approximate weight			0.07	oz.
Moulding device		Case style I-PAK	20U	T04
Marking device		Case style D-PAK	20WT04FN	



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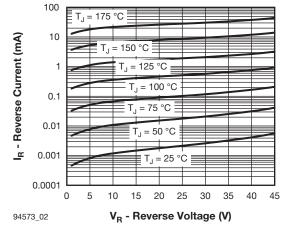


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

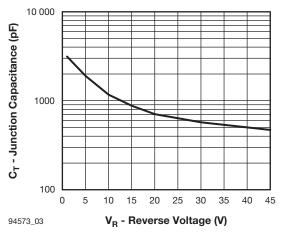


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

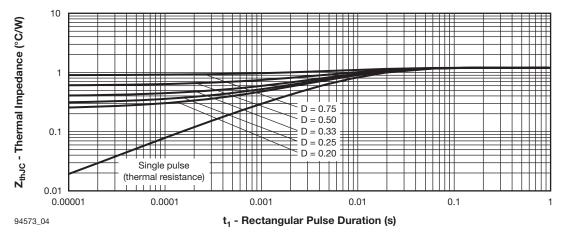
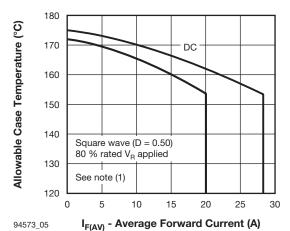


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

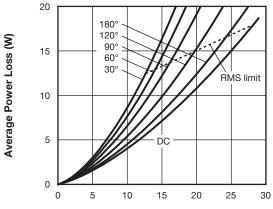




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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

Fig. 6 - Forward Power Loss Characteristics

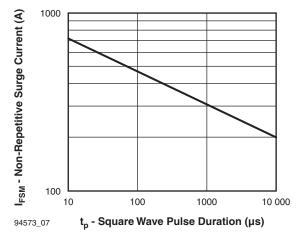


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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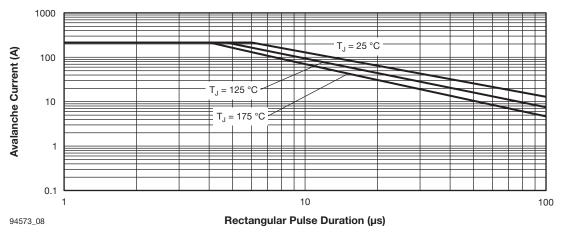


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

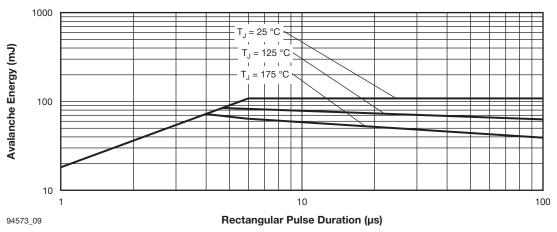


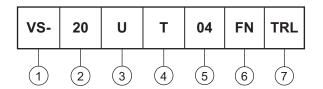
Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 A)

3 - Package:

• U = I-PAK

• W = D-PAK

4 - T = Trench

5 - Voltage code (45 V)

6 - TO-252AA (D-PAK)

7 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

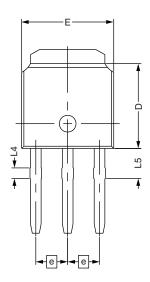
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95024			
Differsions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Doub as adding information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
Part marking information	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95027			

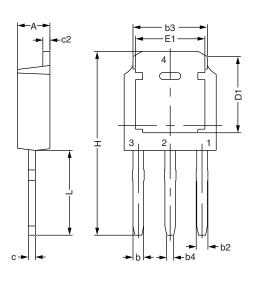


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I-PAK - S

DIMENSIONS FOR I-PAK - S in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41 0.51		0.61		
е	2.286 BSC				
Α	2.20	2.30	2.38		
С	0.40	0.50	0.60		
c2	0.40	0.50	0.60		
D1	5.30	-	-		
E1	4.40	-	-		



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